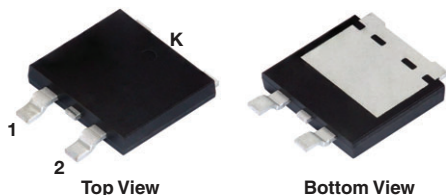


Dual TMBS® (Trench MOS Barrier Schottky) Rectifier

Ultra Low $V_F = 0.34\text{ V}$ at $I_F = 5\text{ A}$

eSMP® Series SMPD (TO-263AC)



FEATURES

- Trench MOS Schottky technology
- Very low profile - typical height of 1.7 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
 - Automotive ordering code; base P/NHM3
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

ADDITIONAL RESOURCES



TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3_X - halogen-free, RoHS-compliant, and AEC-Q101 qualified

("_X" denotes revision code e.g. A, B,...)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 15 A
V_{RRM}	60 V
I_{FSM}	200 A
V_F at $I_F = 15\text{ A}$	0.49 V
T_J max.	150 °C
Package	SMPD (TO-263AC)
Circuit configuration	Common cathode

MAXIMUM RATINGS ($T_A = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	V30D60CL	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	60	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$	30	A
		15	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I_{FSM}	200	A
Voltage rate of change (rated V_R)	dV/dt	10 000	V/ μ s
Operating junction and storage temperature range	T_J, T_{STG}	-40 to +150	°C

ELECTRICAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.44	-	V
	I _F = 7.5 A			0.47	-	
	I _F = 15 A			0.55	0.61	
	I _F = 5 A	T _A = 125 °C		0.34	-	
	I _F = 7.5 A			0.37	-	
	I _F = 15 A			0.49	0.57	
Reverse current per diode	V _R = 60 V	T _A = 25 °C	I _R ⁽²⁾	-	4000	μA
		T _A = 125 °C		35	110	mA

Notes

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: pulse width $\leq 5\text{ ms}$
THERMAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	V30D60CL	UNIT
Typical thermal resistance	per diode	$R_{\theta JC}$	1.8
	per device		0.9
	per device	$R_{\theta JA}^{(1)(2)}$	45

Notes

(1) The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$

(2) Free air, without heatsink

ORDERING INFORMATION (Example)

PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
V30D60CL-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel
V30D60CLHM3_A/I ⁽¹⁾	0.55	I	2000/reel	13" diameter plastic tape and reel

Note

(1) AEC-Q101 qualified

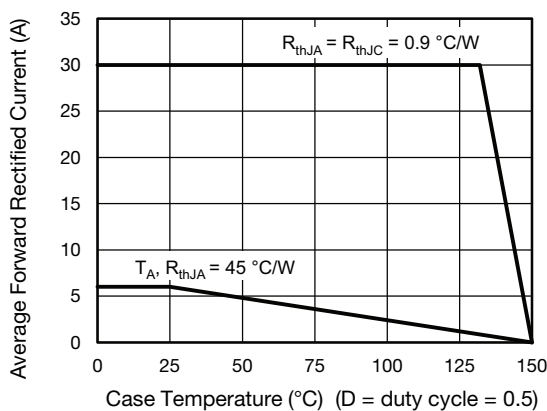
RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)


Fig. 1 - Forward Current Derating Curve

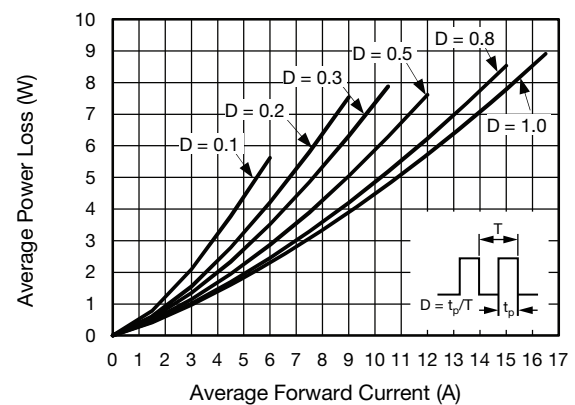


Fig. 2 - Forward Power Loss Characteristics Per Diode

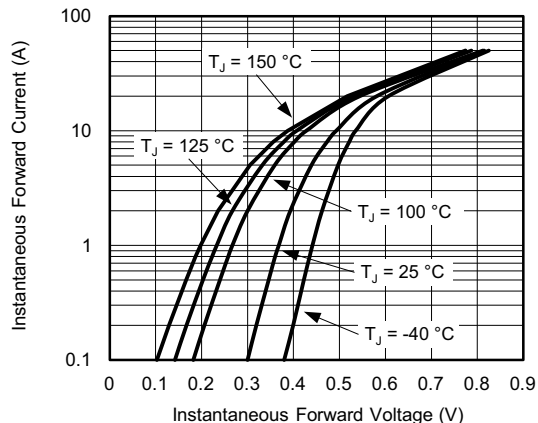


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

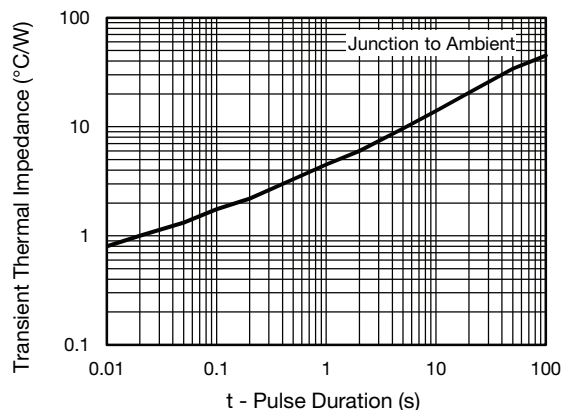


Fig. 6 - Typical Transient Thermal Impedance Per Diode

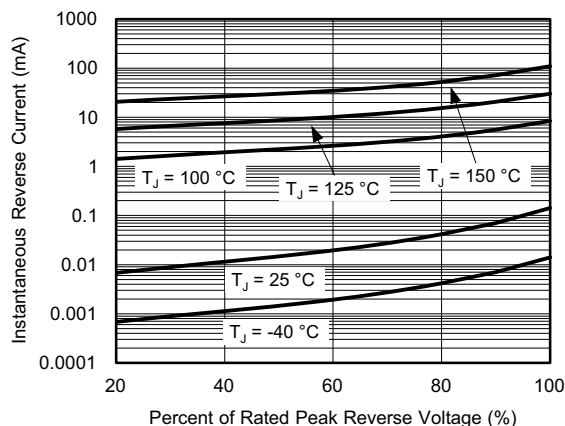


Fig. 4 - Typical Reverse Characteristics Per Diode

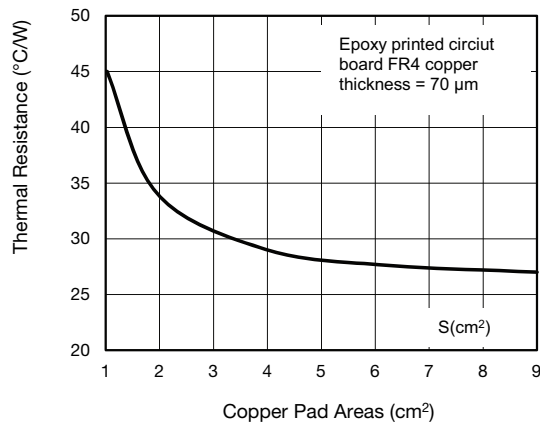


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

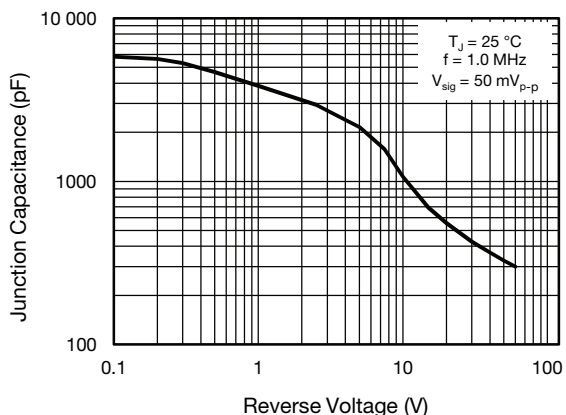
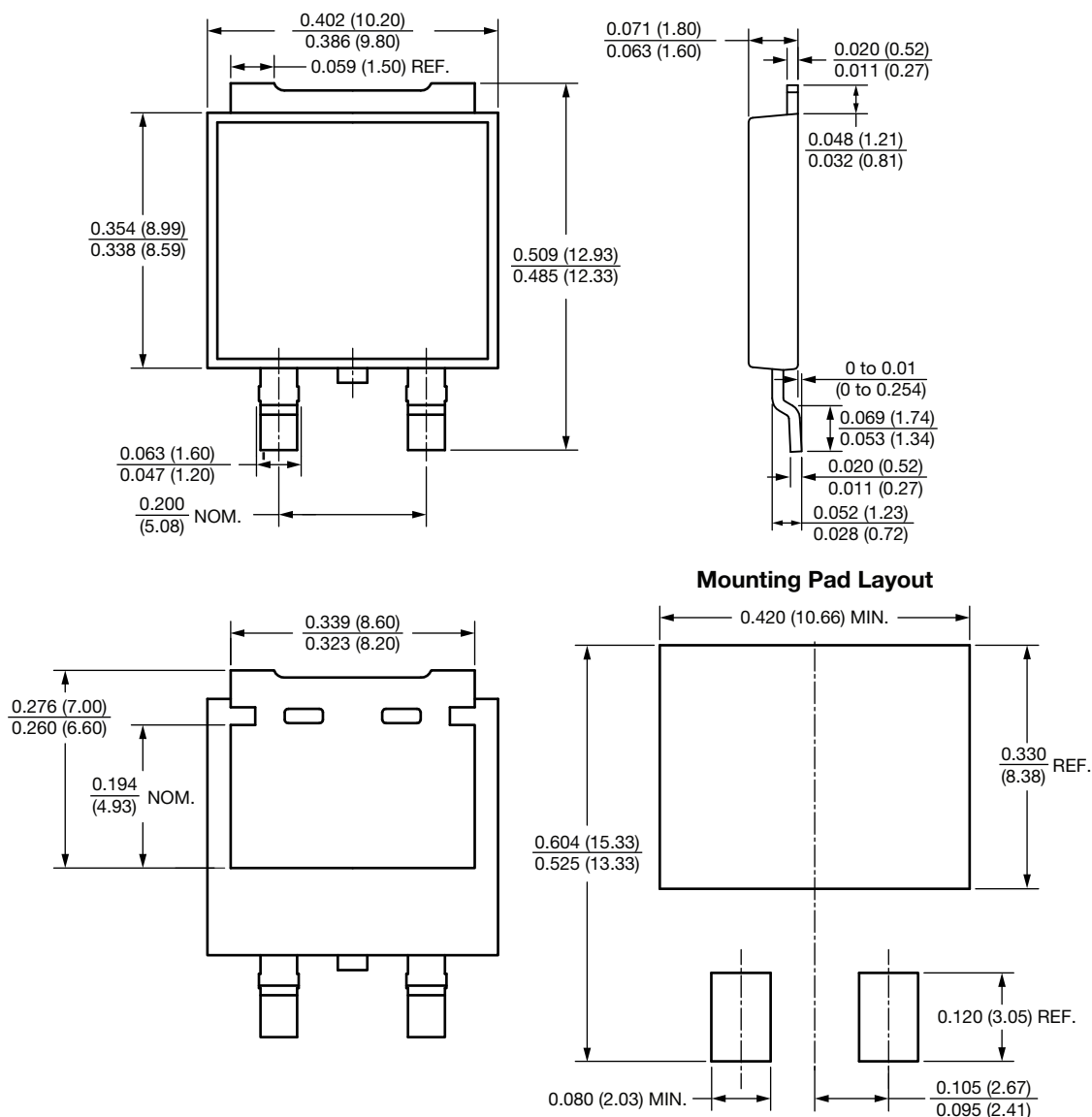


Fig. 5 - Typical Junction Capacitance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

SMPD (TO-263AC)




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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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